

### **Amendments to the Claims**

This listing of claims will replace all prior versions, and listings of claims in the application:

#### **Listing of Claims:**

Claim 1 (Previously Presented): A chip-size semiconductor package, comprising:

- a semiconductor chip;
- a metal pad formed on the semiconductor chip;
- a wafer coat formed over the semiconductor chip;
- a conductive wiring pattern formed on the wafer coat, in which the metal pad is electrically connected to the conductive pattern;
- a molding resin formed over the conductive wiring pattern;
- a conductive post which is formed in the molding resin and is connected to the conductive wiring pattern;
- a terminal which is formed on the molding resin and is connected to the conductive post; and
- a connecting portion between the conductive wiring pattern and the conductive post, the connecting portion having width that gradually decreases toward the conductive wiring pattern,
- the connecting portion having a slit to disperse stress to be applied to the connecting portion.

Claim 2 (Original): A chip-size semiconductor package according to claim 1, wherein the connecting portion is provided with a plurality of slits, which are separated from each other.

Claim 3 (Previously Presented): A chip-size semiconductor package according to claim 2, wherein the slits are rectangular shaped and are arranged to extend radially away from each other.

Claim 4 (Canceled)

Claim 5 (Currently Amended): A chip-size semiconductor package, comprising:

- a semiconductor chip;
- a metal pad formed on the semiconductor chip;
- a wafer coat formed over the semiconductor chip;
- a conductive wiring pattern formed on the wafer coat, in which the metal pad is electrically connected to the conductive pattern;
- a molding resin formed over the conductive wiring pattern;
- a conductive post which is formed in the molding resin and is connected to the conductive wiring pattern;
- a terminal which is formed on the molding resin and is connected to the conductive post;

a connecting portion directly between the conductive wiring pattern and the conductive post, the connecting portion having a width that gradually decreases from a first boundary at the conductive post to a second boundary at the conductive wiring pattern; and

a dummy pattern arranged adjacent the first and second boundaries and along sides of the connecting portion.

Claim 6 (Previously Presented): A chip-size semiconductor package according to claim 5, wherein the dummy pattern is a conductive pattern which is formed during a same process as the conductive wiring pattern and is arranged parallel to the conductive wiring pattern.

Claim 7 (Previously Presented): A chip-size semiconductor package according to claim 5, wherein the dummy pattern comprises two parts respectively arranged along both sides of the connecting portion.

Claim 8 (Canceled)

Claim 9 (Currently Amended): A chip-size semiconductor package, comprising:

a semiconductor chip;

a metal pad formed on the semiconductor chip;

a wafer coat formed over the semiconductor chip;

a conductive wiring pattern formed on the wafer coat, in which the metal pad is electrically connected to the conductive pattern;

a molding resin formed over the conductive wiring pattern;

a conductive post which is formed in the molding resin and is connected to the conductive wiring pattern;

a terminal which is formed on the molding resin and is connected to the conductive post; and

a connecting portion directly between the conductive wiring pattern and the conductive post, the connecting portion having a width that gradually decreases from a first boundary at the conductive post to a second boundary at the conductive wiring pattern,

wherein a dent is formed at and around the connecting portion.

Claim 10 (Previously Presented): A chip-size semiconductor package according to claim 9, wherein the dent is square shaped.

Claim 11 (Canceled)

Claim 12 (Currently Amended): A chip-size semiconductor package, comprising:

a semiconductor chip;

a metal pad formed on the semiconductor chip;

a wafer coat formed over the semiconductor chip;

a conductive wiring pattern formed on the wafer coat, in which the metal pad is electrically connected to the conductive wiring pattern;

a molding resin formed over the conductive wiring pattern;

a conductive post which is formed in the molding resin and is connected to the conductive wiring pattern;

a terminal which is formed on the molding resin and is connected to the conductive post; and

a connecting portion directly between the conductive wiring pattern and the conductive post, the connecting portion having a width that gradually decreases from a first boundary at the conductive post to a second boundary at the conductive wiring pattern,

the connecting portion having a first region extending outwardly from the conductive post and a second region extending in a perpendicular direction from the first region, the second region extending from the connecting portion.

Claim 13 (Previously Presented): A chip-size semiconductor package according to claim 12, further comprising a plurality of projecting parts each of which extends in the perpendicular direction from the conductive wiring pattern.

Claim 14 (Currently Amended): A chip-size semiconductor package according to claim 13, wherein the second ~~regions extend~~ region extends from both sides of the first region.

Claims 15-17 (Canceled)